

SEMICONDUCTOR TM

# BDX33/A/B/C

# **Power Linear and Switching Applications**

- High Gain General Purpose
- Power Darlington TR
- Complement to BDX34/34A/34B/34C respectively



1.Base 2.Collector 3.Emitter

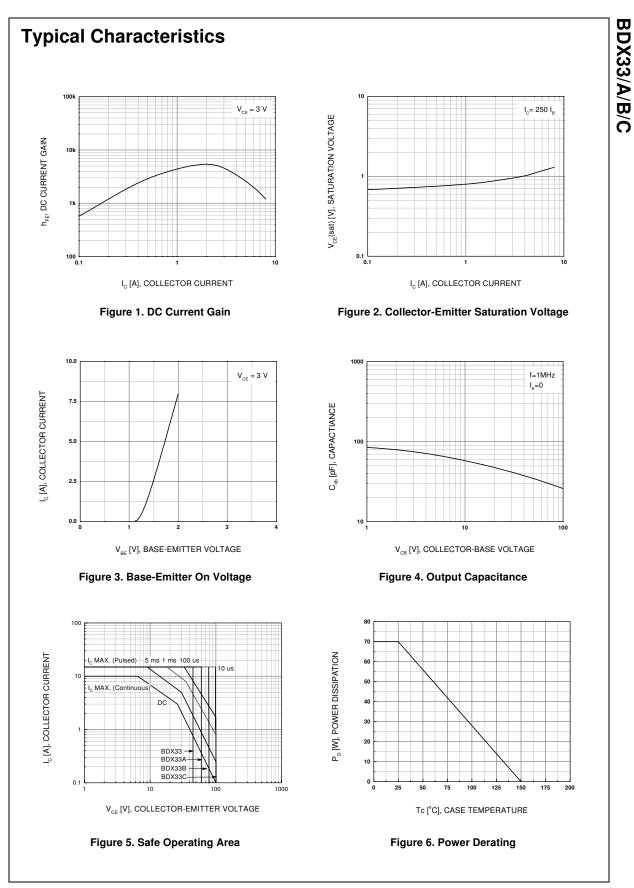
# NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage		
	: BDX33	45	V
	: BDX33A	60	V
	: BDX33B	80	V
	: BDX33C	100	V
V <sub>CEO</sub>	Collector-Emitter Voltage		
	: BDX33	45	V
	: BDX33A	60	V
	: BDX33B	80	V
	: BDX33C	100	V
I <sub>C</sub>	Collector Current (DC)	10	Α
CP	*Collector Current (Pulse)	15	А
I <sub>B</sub>	Base Current	0.25	А
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	70	W
ГJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 65 ~ 150	°C

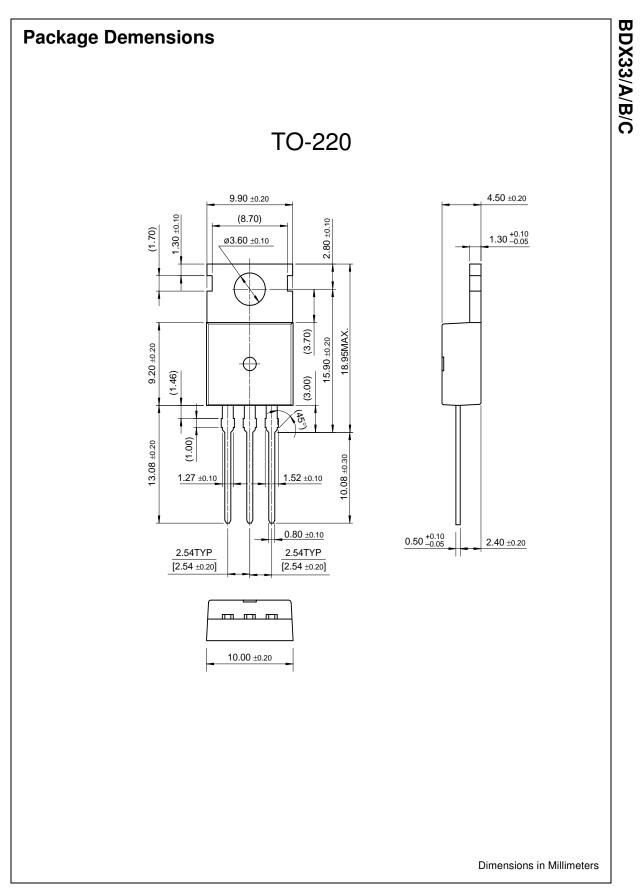
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V <sub>CEO</sub> (sus)	* Collector-Emitter Sustaining Voltage : BDX33 : BDX33A : BDX33A : BDX33B : BDX33C	l <sub>C</sub> = 100mA l <sub>B</sub> = 0	45 60 80 100			
V <sub>CER</sub> (sus)	* Collector-Emitter Sustaining Voltage : BDX33 : BDX33A : BDX33B : BDX33B : BDX33C	l <sub>C</sub> = 100mA, I <sub>B</sub> = 0 R <sub>BE</sub> = 100Ω	45 60 80 100			V V V V
V <sub>CEV</sub> (sus)	* Collector-Emitter Sustaining Voltage : BDX33 : BDX33A : BDX33B : BDX33B	l <sub>C</sub> = 100mA, I <sub>B</sub> = 0 V <sub>BE</sub> = 1.5V	45 60 80 100			
I <sub>CBO</sub>	Collector Cut-off Current : BDX33 : BDX33A : BDX33B : BDX33C	$V_{CB} = 45V, I_E = 0$ $V_{CB} = 60V, I_E = 0$ $V_{CB} = 80V, I_E = 0$ $V_{CB} = 100V, I_E = 0$			0.2 0.2 0.2 0.2	mA mA mA mA
CEO	Collector Cut-off Current : BDX33 : BDX33A : BDX33B : BDX33B : BDX33C	$V_{CE} = 22V, I_B = 0$ $V_{CE} = 30V, I_B = 0$ $V_{CE} = 40V, I_B = 0$ $V_{CE} = 50V, I_B = 0$			0.5 0.5 0.5 0.5	mA mA mA mA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 5V, I_C = 0$			5	mA
h <sub>FE</sub>	* DC Current Gain : BDX33/34 : BDX33B/33C	$V_{CE} = 3V$ , $I_C = 4A$ $V_{CE} = 3V$ , $I_C = 3A$	750 750			
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage : BDX33/33A : BDX33B/33C	I <sub>C</sub> = 4A, I <sub>B</sub> = 8mA I <sub>C</sub> = 3A, I <sub>B</sub> = 6mA			2.5 2.5	v v
V <sub>BE</sub> (on)	* Base-Emitter ON Voltage : BDX33/33A : BDX33B/33C	$V_{CE} = 3V$ , $I_C = 4A$ $V_{CE} = 3V$ , $I_C = 3A$			2.5 2.5	v v
VF	* Parallel Diode Forward Voltage	I <sub>F</sub> = 8A			4	V

BDX33/A/B/C



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